

GSMBT5401 PNP EPITAXIAL PLANAR TRANSISTOR

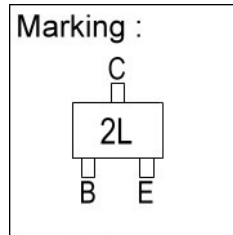
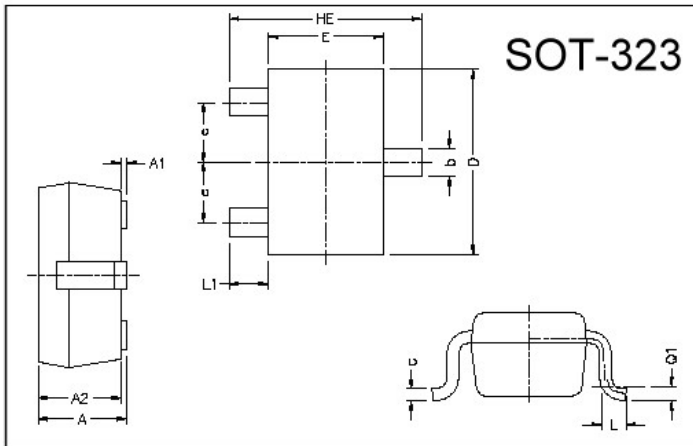
Description

The GSMBT5401 is designed for general purpose applications requiring high breakdown voltage.

Features

- High Collector-Emitter Breakdown Voltage ($BV_{CEO}=-150V @ I_C=-1mA$)
- Complementary to GSMBT5551

Package Dimensions



REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	0.80	1.10	L1	0.42	REF.
A1	0	0.10	L	0.15	0.35
A2	0.80	1.00	b	0.25	0.40
D	1.80	2.20	c	0.10	0.25
E	1.15	1.35	e	0.65 REF.	
HE	1.80	2.40	Q1	0.15 BSC.	

Absolute Maximum Ratings at $T_a = 25^\circ C$

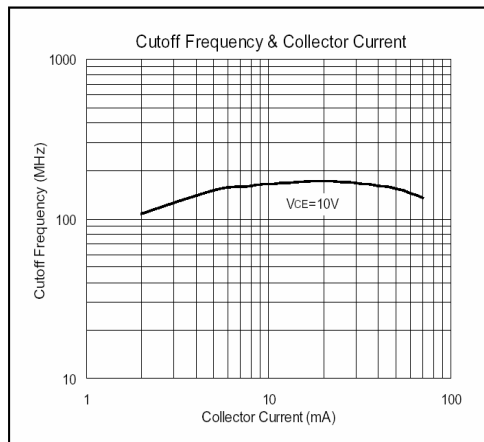
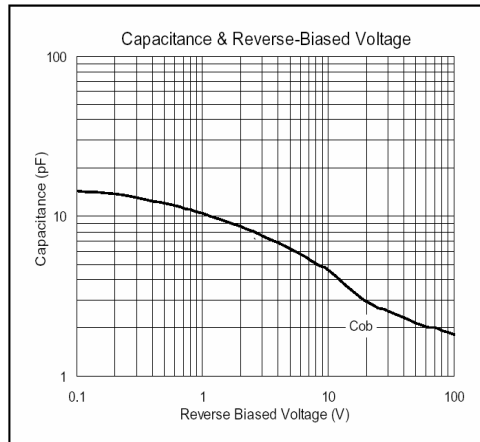
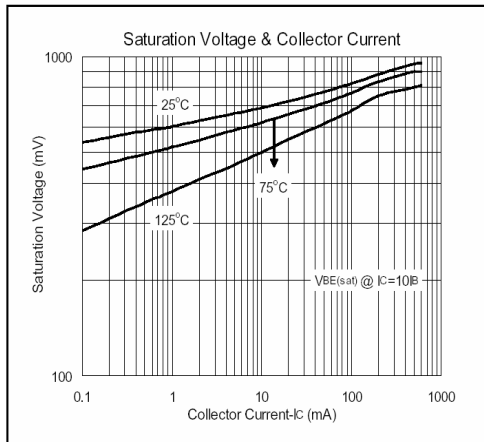
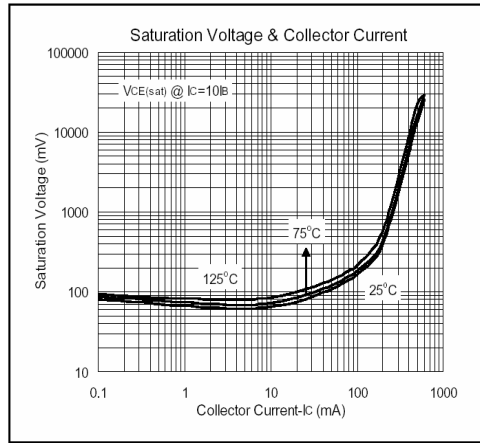
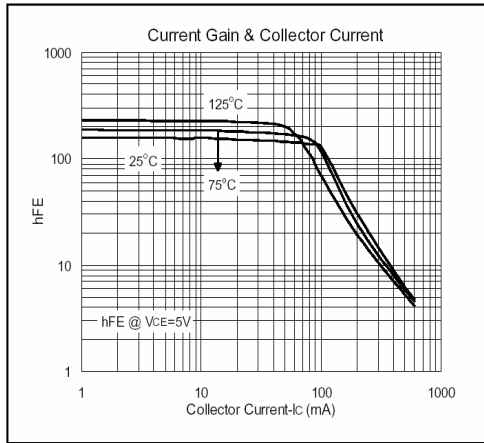
Parameter	Symbol	Ratings	Unit
Junction Temperature	T_j	+150	$^\circ C$
Storage Temperature	T_{stg}	-55~+150	$^\circ C$
Collector to Base Voltage	V_{CBO}	-160	V
Collector to Emitter Voltage	V_{CEO}	-150	V
Emitter to Base Voltage	V_{EBO}	-5	V
Collector Current	I_C	-600	mA
Total Power Dissipation	P_D	225	mW

Electrical Characteristics ($T_a = 25^\circ C$)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BV_{CBO}	-160	-	-	V	$I_C=-100\mu A, I_E=0$
BV_{CEO}	-150	-	-	V	$I_C=-1mA, I_B=0$
BV_{EBO}	-5	-	-	V	$I_E=-10\mu A, I_C=0$
I_{CBO}	-	-	-50	nA	$V_{CB}=-120V, I_E=0$
* $V_{CE(sat)1}$	-	-	-200	mV	$I_C=-10mA, I_B=-1mA$
* $V_{CE(sat)2}$	-	-	-500	mV	$I_C=-50mA, I_B=-5mA$
* $V_{BE(sat)1}$	-	-	-1	V	$I_C=-10mA, I_B=-1mA$
* $V_{BE(sat)2}$	-	-	-1	V	$I_C=-50mA, I_B=-5mA$
* h_{FE1}	50	-	-		$V_{CE}=-5V, I_C=-1mA$
* h_{FE2}	60	-	240		$V_{CE}=-5V, I_C=-10mA$
* h_{FE3}	50	-	-		$V_{CE}=-5V, I_C=-50mA$
fT	100	-	300	MHz	$V_{CE}=-10V, I_C=-10mA, f=100MHz$
Cob	-	-	6	pF	$V_{CB}=-10V, I_E=0, f=1MHz$

* Pulse Test: Pulse Width $\leq 380\mu s$, Duty Cycle $\leq 2\%$

Characteristics Curve



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